

High voltage discharge, High speed switching, Low Noise (-60V, -3A)

2SA2073

Features

- 1) High speed switching. (tf : Typ. : 20ns at Ic = -3A)
- 2) Low saturation voltage, typically.

(Typ.: -200mV at Ic=-2.0A, IB=-200mA)

- 3) Strong discharge power for inductive load and capacitance load.
- 4) Low Noise.
- 5) Complements the 2SC5826.

Applications

High speed switching, Low noise

Structure

PNP Silicon epitaxial planar transistor

Packaging specifications

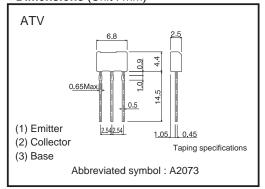
	Package	Taping
Туре	Code	TV2
	Basic ordering unit (pieces)	2500
2SA2073		0

●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	-60	V	
Collector-emitter voltage		Vceo	-60	V	
Emitter-base voltage		VEBO	-6	V	
Collector current	DC	Ic	-3	А	
	Pulsed	Іср	-6	A *	
Power dissipation		Pc	1.0	W	
Junction temperature		tj	150	°C	
Range of storage temperature		tstg	-55 to 150	°C	

^{*}Pw=10ms

●Dimensions (Unit: mm)



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Collector-emitter breakdown voltage	BVceo	-60	_	_	V	Ic=-1mA
Collector-base breakdown voltage	ВУсво	-60	_	_	V	Ic=-100μA
Emitter-base breakdown voltage	ВVево	-6	_	_	V	IE=-100μA
Collector cut-off current	Ісво	_	_	-1.0	μΑ	Vcb=-40V
Emitter cut-off current	ІЕВО	_	_	-1.0	μΑ	V _{EB} =-4V
Collector-emitter saturation voltage	VCE (sat)	_	-200	-500	mV	Ic=-2.0A *1
Collector-entitler saturation voltage						I _B =-200mA
DC current gain	hfe	120	_	270	_	Vce=-2V
						Ic=-100mA
	fτ	_	200	_	MHz	Vc=-10V *1
Transistor frequency						IE=100mA
						f=10MHz
	Cob	_	40	_	pF	VcB=-10V
Collector output capacitance						IE=0mA
						f=1MHz
Turn-on time	ton	_	20	_	ns	Ic=-3A *2
Storage time	tstg	_	130	_	ns	I _{В1} =-300mA I _{В2} =300mA
Fall time	tf	_	20	-	ns	Vcc≃ –25V

●hFE RANK

Q	
120–270	

•Electrical characteristic curves

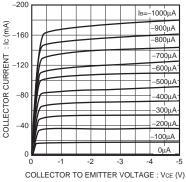


Fig.1 Typical output characteristics

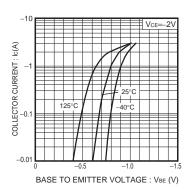


Fig.2 Grounded emitter propagation characteristics

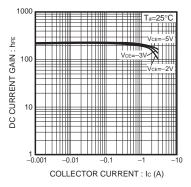


Fig.3 DC current gain vs.collector current (I)

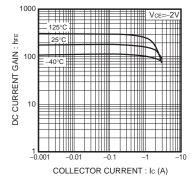


Fig.4 DC current gain vs.collector current (II)

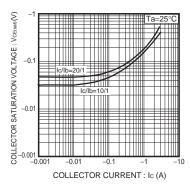


Fig.5 Collector-emitter saturation voltage vs.collector current (I)

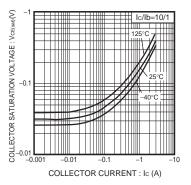


Fig.6 Collector-emitter saturation voltage vs.collector current (II)

^{*1} Single pulse *2 See switching characteristics measurement circuits

2SA2073 Data Sheet

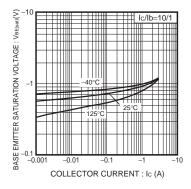


Fig.7 Base-emitter saturation voltage vs. collector current

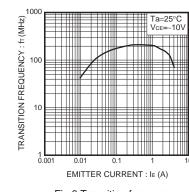


Fig.8 Transition frequency

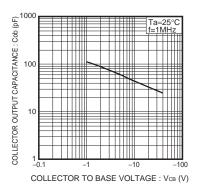


Fig.9 Collector output capacitance

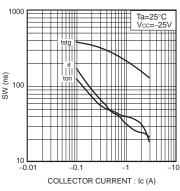
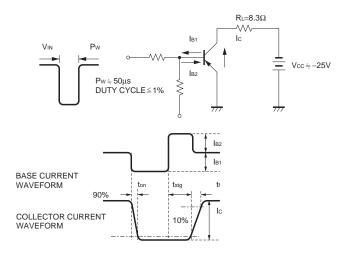


Fig.10 Switching Time

•Switching characteristics measurement circuits



Notes

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